

View Online at <https://aerobasegroup.com/nsn/5961-00-434-2293>

Inclosure Material:

Metal

Overall Length:

Between 0.660 inches and 0.785 inches

Overall Height:

0.200 inches

Overall Width:

Between 0.220 inches and 0.280 inches

Component Name And Quantity:

4 transistor

Mounting Method:

Press fit

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

5.0 emitter to base, rms all transistor and 40.0 collector to emitter voltage/static/base open all transistor

Current Rating Per Characteristic:

1.00 amperes source cutoff current all transistor

Power Rating Per Characteristic:

500.0 milliwatts small-signal input power, common-collector absolute all transistor

Maximum Operating Temperature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

All transistor junction pattern arrangement: pnp

Terminal Type And Quantity:

14 ribbon

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

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